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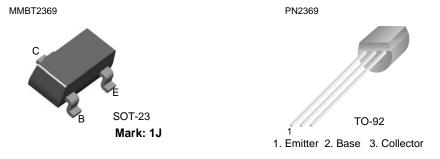
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February 2008

# MMBT2369 / PN2369 **NPN Switching Transistor**

- This device is designed for high speed saturated switching at collector currents of 10mA to 100mA.
- · Sourced from process 21.



### Absolute Maximum Ratings \* Ta = 25xC unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	15	V	
V <sub>CBO</sub>	Collector-Base Voltage	40	V	
V <sub>EBO</sub>	Emitter-Base Voltage	4.5	V	
I <sub>C</sub>	Collector Current - Continuous	200	mA	
I <sub>CP</sub>	**Collector Current (Pulse)	400	mA	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ 150	°C	

<sup>\*</sup> This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

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<sup>\*\*</sup> Pulse Test: Pulse Width £ 300ms, Duty Cycle £ 2.0%

<sup>1)</sup> These rating are based on a maximum junction temperature of 150 degrees C.

<sup>2)</sup> These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

<sup>\*</sup> Device mounted on FR-4PCB 1.6" ¥ 1.6" ¥ 0.06".

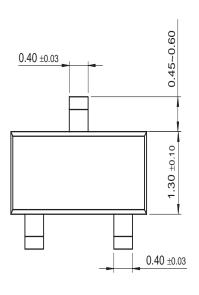
## **Electrical Characteristics** $T_a = 25$ °C unless otherwise noted

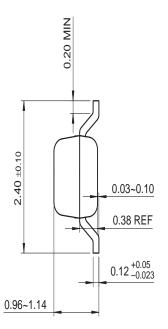
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage *	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0	15		V
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	$I_C = 10\mu A, V_{BE} = 0$	40		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 10 \mu A, I_{E} = 0$	40		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	4.5		V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 20V, I <sub>E</sub> = 0 V <sub>CB</sub> = 20V, I <sub>E</sub> = 0, T <sub>a</sub> = 125°C		0.4 30	μA μA
On Charact	eristics		•	•	•
h <sub>FE</sub>	DC Current Gain *	$I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$ $I_C = 100 \text{mA}, V_{CE} = 2.0 \text{V}$	40 20	120	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage *	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA		0.25	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA	0.7	0.85	V
	al Characteristics				
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 5.0V, I_{E} = 0, f = 1.0MHz$		4.0	pF
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5V, I_C = 0, f = 1.0MHz$		5.0	pF
h <sub>fe</sub>	Small -Signal Current Gain	$I_C$ = 10mA, $V_{CE}$ = 10V, $R_G$ = 2.0kΩ, $f$ = 100MHz	5.0		
Switching C	Characteristics		•	•	•
t <sub>s</sub>	Storage Time	$I_{B1} = I_{B2} = I_C = 10 \text{mA}$		13	ns
t <sub>on</sub>	Turn-On Time	$V_{CC} = 3.0V, I_{C} = 10mA, I_{B1} = 3.0mA$		12	ns
t <sub>off</sub>	Turn-Off Time	$V_{CC} = 3.0V$ , $I_{C} = 10$ mA, $I_{B1} = 3.0$ mA, $I_{B2} = 1.5$ mA		18	ns

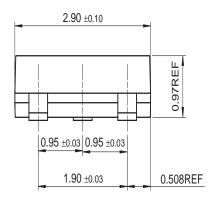
<sup>\*</sup> Pulse Test: Pulse Width £ 300ms, Duty Cycle £ 2.0%

# **Package Dimensions**

# **SOT-23**



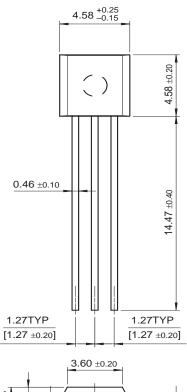


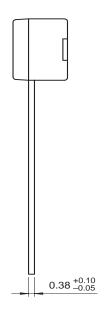


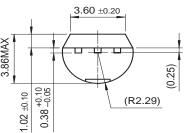
**Dimensions in Millimeters** 

# **Package Dimensions (Continued)**

TO-92







Dimensions in Millimeters





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